Introduction
The class of organic-inorganic halide perovskite semiconductors has attracted a lot of attention due to their outstanding optical and electrical properties. High performance photovoltaic devices (PVs) with excellent power conversion efficiencies (>22%) and high performance light emitting diodes (LEDs) have been reported recently. However, the physics and chemistry of organic-inorganic halide perovskite semiconductors and related devices are not well understood. For solar cells and LEDs radiative recombination is the most important ingredient for high performance. Therefore, a detailed understanding of photon absorption and recombination of photo-excited states in perovskite materials is important to study the quality and potential of synthesized materials.

Experimental
Perovskite layers with the chemical composition CH$_3$NH$_3$PbI$_3$ are deposited on sapphire substrates from solution. Process details are described in [1]. Samples are attached to a copper holder and mounted on the cold finger of a closed-cycle helium cryostat. A pulsed, frequency-doubled Nd-YAG laser (Innolas Spotlight Compact 100, 10 Hz) is applied as excitation source. The pulse energy is adjusted with neutral density filters to achieve 0.1 mJ/cm$^2$ at the sample position. The sample emission is collected with a lens and guided to the detection unit with an optical fiber. A long pass filter (550 nm) removes the excitation light before the collected radiation is fed into a monochromator (Andor Shamrock 303i, grating 500 nm blaze, 150 lines/mm) and detected with an intensified charge-coupled device (Andor iStar DH320T-18U-73). Spectra are recorded with 2.5 ns gate width and 2.5 ns gate step. A sketch of the experimental setup is shown in Figure 1.

Results
Figure 2 shows the photoluminescence spectra recorded at different delay times. The emission intensity increases at lower temperatures. At 125 K the emission shifts to higher energies and the peak splits into two features.

Analyzing the decay kinetics is very challenging due to complicated line-shapes and several different decay times can be extracted from the recorded spectra. Figure 3 shows integrals of individual spectra at 5 K, 125 K and 295 K versus time.

Application Note
Figure 2: Photoluminescence spectra of a MAPbI$_3$ film recorded after different delays and different temperatures.

Figure 3: Photoluminescence kinetics of a MAPbI$_3$ sample recorded at different temperatures.

Figure 1: Experimental setup
Application Note

All spectra show at least one short-lived and one long-lived component and the decay appears to be faster at low temperatures.

Summary
In this application note photoluminescence experiments on thin perovskite layers are described. We find that this perovskite semiconductor exhibits a complicated temperature dependence of the PL spectra suggesting that the system undergoes various phase transitions. The applied experimental arrangement is ideal for the performed experiments as the spectral and the time-domain kinetics can be studied at the same time.

References

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